Diode Semiconductor Device - Page 1 of 1



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### **Inclosure Material:**

Glass

**Overall Length:** 

0.195 inches

## **Terminal Length:**

1.000 inches

### **Overall Diameter:**

0.185 inches

### **Function For Which Designed:**

Transient suppressor

### Mounting Method:

Terminal

### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

37.1 breakdown voltage, dc and 29.7 working peak reverse voltage

### Current Rating Per Characteristic:

28.00 amperes source cutoff current pascal

### **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector major

### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Terminal Type And Quantity:**

2 uninsulated wire lead

### **Specification Data:**

81349-mil-s-19500/516 government specification

Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

No

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